







SN74ACT564 SCAS549D - NOVEMBER 1995 - REVISED FEBRUARY 2024

SN74ACT564 Octal D-Type Edge-Triggered Flip-Flops with 3-State Outputs

1 Features

- Operation of 4.5V to 5.5V V_{CC}
- Inputs accept voltages to 5.5V
- Max t_{pd} of 8.5ns at 5V
- Inputs are TTL-voltage compatible
- 3-state inverted outputs drive bus lines directly
- Flow-through architecture to optimize PCB layout
- Full parallel access for loading

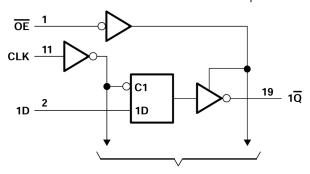
2 Description

The 'ACT564 devices are octal D-type edge-triggered flip-flops that feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are particularly suitable implementing buffer registers, I/O bidirectional bus drivers, and working registers.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE(2)	BODY SIZE(3)
	DW (SOIC, 20)	12.8mm × 10.3mm	12.8mm × 7.5mm
SNI74ACTEGA	N (PDIP, 20)	24.33mm × 9.4mm	24.33mm × 6.35mm
SN74ACT564	NS (SOP, 20) 12.6		12.6mm × 5.3mm
	PW (TSSOP, 20)	6.5mm × 6.4mm	6.5mm × 4.4mm

- For more information, see Section 10.
- The package size (length × width) is a nominal value and includes pins, where applicable.
- The body size (length × width) is a nominal value and does (3)not include pins.



To Seven Other Channels **Logic Diagram (Positive Logic)**



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3 Pin Configuration and Functions

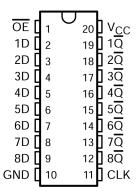


Figure 3-1. SN74ACT564 DB, DW, N, NS, or PW Package (Top View)

Table 3-1. Pin Functions

PIN		TVDE	Description	
NO.	NAME	TYPE	Description	
1	ŌĒ	I	Clear all channels, active low	
2	1D	I	Channel 1, D input	
3	2D	I	Channel 2, D input	
4	3D	1	Channel 3, D input	
5	4D	1	Channel 4, D input	
6	5D	Ţ	Channel 5, D input	
7	6D	1	Channel 6, D input	
8	7D	1	Channel 7, D input	
9	8D	1	Channel 8, D input	
10	GND	_	Ground	
11	CLK	1	Clock Pin	
12	8Q	0	Channel 8, Q output	
13	7Q	0	Channel 7, Q output	
14	6Q	0	Channel 6, Q output	
15	5Q	0	Channel 5, Q output	
16	4Q	0	Channel 4, Q output	
17	3Q	0	Channel 3, Q output	
18	2Q	0	Channel 2, Q output	
19	1Q	0	Channel 1, Q output	
20	V _{CC}	_	Power Pin	



4 Specifications

4.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	7	V
V _I ⁽²⁾	Input voltage range		-0.5	V _{CC} + 0.5	V
V _O (2)	Output voltage range		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	(V _I < 0 or V _I > V _{CC})		±20	mA
I _{OK}	Output clamp current	$(V_O < 0 \text{ or } V_O > V_{CC})$		±20	mA
Io	Continuous output current	(V _O = 0 to V _{CC})		±50	mA
	Continuous current through V _{CC} or GND			±200	mA
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

4.2 Recommended Operating Conditions

(over operating free-air temperature range (unless otherwise noted)(1)

		SN74AC	T564	UNIT
		MIN	MAX	UNII
V _{CC}	Supply voltage	4.5	5.5	V
V _{IH}	High-level input voltage	2		V
V _{IL}	Low-level input voltage		0.8	V
VI	Input voltage	0	V _{CC}	V
Vo	Output voltage	0	V _{CC}	V
I _{OH}	High-level output current		-24	mA
I _{OL}	Low-level output current		24	mA
Δt/Δν	Input transition rise or fall rate		8	ns/V
T _A	Operating free-air temperature	-40	85	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND for proper device operation. Refer to the TI application report *Implications* of Slow or Floating CMOS Inputs, literature number SCBA004.

4.3 Thermal Information

		SN74ACT564					
THERMAL METRIC(1)		DB (SSOP)	DW (SOIC)	N (PDIP)	NS (SO)	PW (TSSOP)	UNIT
		20 PINS	20 PINS	20 PINS	20 PINS	20 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	70	101.2	69	106.2	126.2	°C/W

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).

Product Folder Links: SN74ACT564

²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



4.4 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST COMPLETIONS	.,	T,	λ = 25°C		SN74ACT564		UNIT
PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	MIN	MAX	UNII
	1 - 50.04	4.5 V	4.4	4.49		4.4		
	I _{OH} = -50 μA	5.5 V	5.4	5.49		5.4		
N/	L = 24 mA	4.5 V	3.86			3.76		V
V _{OH}	$I_{OH} = -24 \text{ mA}$	5.5 V	4.86			4.76		V
	$I_{OH} = -50 \text{ mA}^{(1)}$	5.5 V						
	$I_{OH} = -75 \text{ mA}^{(1)}$	5.5 V				3.85		
	I = 50A	4.5 V			0.1		0.1	
	I _{OL} = 50μA	5.5 V			0.1		0.1	
N/	I _{OL} = 24 mA	4.5 V			0.36		0.44	V
V _{OL}		5.5 V			0.36		0.44	
	I _{OL} = 50 mA ⁽¹⁾	5.5 V						
	I _{OL} = 75 mA ⁽¹⁾	5.5 V					1.65	
I _{OZ}	V _O = V _{CC} or GND	5.5 V			±0.25		±2.5	μA
I _I	V _I = V _{CC} or GND	5.5 V			±0.1		±1	μA
I _{CC}	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40	μA
ΔI _{CC} (2)	One input at 3.4 V, Other inputs at GND or $V_{\rm CC}$	5.5 V		0.6			1.5	mA
Ci	V _I = V _{CC} or GND	5 V		4.5				pF
Co	V _O = V _{CC} or GND	5 V		15				pF

⁽¹⁾ Not more than one output should be tested at a time, and the duration of the test should not exceed 2 ms.

4.5 Timing Requirements

over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

		T _A = 25°C		SN74ACT564		UNIT
		MIN	MAX	MIN	MAX	UNIT
f _{clock}	Clock frequency		85		75	MHz
t _w	Pulse duration, CLK high or low	3		3.5		ns
t _{su}	Setup time, data before CLK↑	2.5		3		ns
t _h	Hold time, data after CLK↑	1		1		ns

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⁽²⁾ This is the increase in supply current for each input that is at one of the specified TTL voltage levels, rather than 0 V or V_{CC}.



4.6 Switching Characteristics

over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM (INPUT)	T _A = 25°C			SN74AC	UNIT		
PARAMETER	PROW (INPUT)	TO (OUTPUT)	MIN	TYP	MAX	MIN	MAX	ONIT
f _{max}			85	90		75		MHz
t _{PLH}	CLK	Q	2	6.5	10.5	1.5	11.5	ns
t _{PHL}	OLK	Q Q	1.5	6	9.5	1.5	10.5	115
t _{PZH}	ŌĒ	Q	1.5	5.5	9	1.5	9.5	ns
t _{PZL}	OE	Q	1.5	5.5	8.5	1	9.5	115
t _{PHZ}	ŌĒ	Q	1.5	7	10.5	1.5	11.5	ns
t _{PLZ}	OE .		1.5	5	8	1	8.5	115

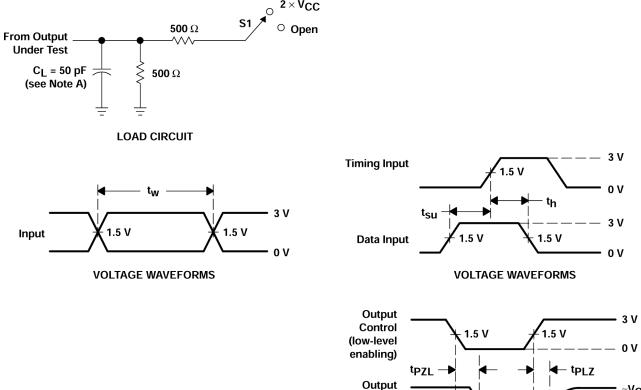
4.7 Operating Characteristics

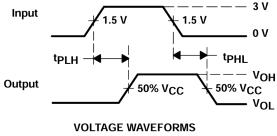
 V_{CC} = 5 V, T_A = 25°C

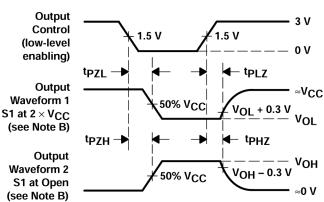
PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd} Power dissipation capacitance	$C_L = 50 \text{ pF}, \qquad f = 1 \text{ MHz}$	50	pF

Product Folder Links: SN74ACT564

5 Parameter Measurement Information







VOLTAGE WAVEFORMS

- A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, ZO = 50 Ω, tr ≤ 2.5 ns, tf ≤ 2.5 ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 5-1. Load Circuit and Voltage Waveforms

S1
Open
2 × V _{CC}
Open

6 Detailed Description

6.1 Overview

On the positive transition of the clock (CLK) input, the \overline{Q} outputs are set to the complements of the logic levels set up at the data (D) inputs.

A buffered output-enable (OE) input places the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

OE does not affect internal operations of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

For specified high-impedance state during power up or power down, \overline{OE} must be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

6.2 Functional Block Diagram

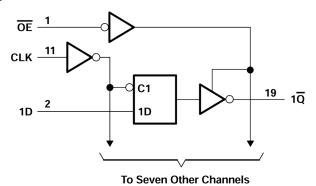


Figure 6-1. Logic Diagram (Positive Logic)

6.3 Device Functional Modes

Table 6-1. Function Table (Each Flip-flop)

	INPUTS	OUTPUT Q	
ŌĒ	CLK	D	OUTFUT
L	1	Н	L
L	1	L	Н
L	H or L	Х	Q ₀
Н	Х	Х	Z

Product Folder Links: SN74ACT564

7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Power Supply Recommendations

The power supply can be any voltage between the min and max supply voltage rating located in Section 4.2.

Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, TI recommends 0.1 μ F and if there are multiple V_{CC} terminals, then TI recommends .01 μ F or .022 μ F for each power terminal. It is okay to parallel multiple bypass capacitors to reject different frequencies of noise. A 0.1 μ F and 1 μ F are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

7.2 Layout

7.2.1 Layout Guidelines

When using multiple bit logic devices inputs should not ever float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified below are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} whichever make more sense or is more convenient. It is generally okay to float outputs unless the part is a transceiver. If the transceiver has an output enable pin it will disable the outputs section of the part when asserted. This does not disable the input section of the IOs so they cannot float when disabled.

7.2.2 Layout Example

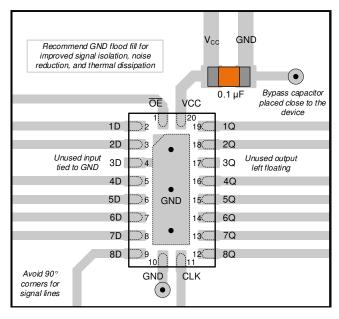


Figure 7-1. Example layout for the SN74ACT564



8 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

8.1 Documentation Support (Analog)

8.1.1 Related Documentation

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 8-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY	
SN74ACT564	Click here	Click here	Click here	Click here	Click here	

8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

8.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

8.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

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9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	Changes from Revision C (August 2023) to Revision D (February 2024)	Page
	Added body size to Package Information table	
• —	Updated RθJA values: DW = 58 to 101.2, NS = 60 to 106.2, PW = 83 to 126.2, all values in °C/W	4
С	Changes from Revision B (November 2002) to Revision C (August 2023)	Page
_	Changes from Revision B (November 2002) to Revision C (August 2023) Added Package Information table, Pin Functions table, Thermal Information table, Device Functional Mo Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information	
_	Added Package Information table, Pin Functions table, Thermal Information table, Device Functional Mo	des,

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74ACT564DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ACT564	Samples
SN74ACT564N	ACTIVE	PDIP	N	20	20	RoHS & Non-Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74ACT564N	Samples
SN74ACT564NSR	ACTIVE	SO	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ACT564	Samples
SN74ACT564PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AD564	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and



PACKAGE OPTION ADDENDUM

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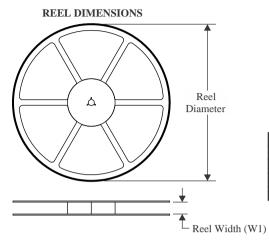
continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

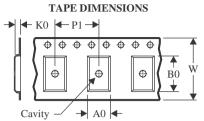
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





_	Tanana and a same and a same and a same and a same a s
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

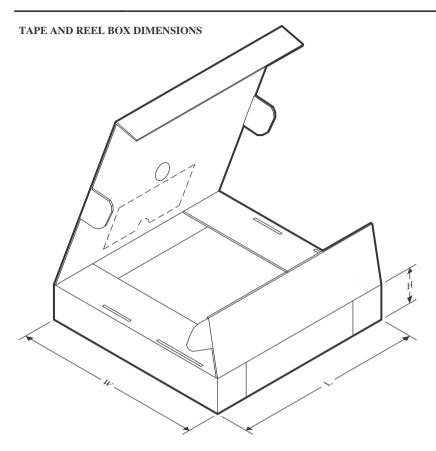


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ACT564DWR	SOIC	DW	20	2000	330.0	24.4	10.9	13.3	2.7	12.0	24.0	Q1
SN74ACT564DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74ACT564NSR	so	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74ACT564NSR	so	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74ACT564PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74ACT564PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1



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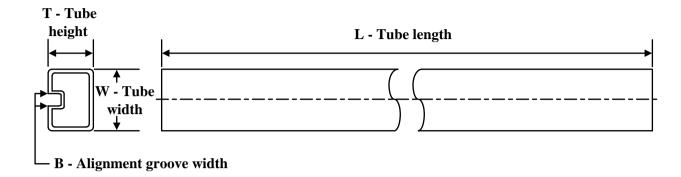
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ACT564DWR	SOIC	DW	20	2000	356.0	356.0	45.0
SN74ACT564DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74ACT564NSR	SO	NS	20	2000	367.0	367.0	45.0
SN74ACT564NSR	SO	NS	20	2000	356.0	356.0	45.0
SN74ACT564PWR	TSSOP	PW	20	2000	353.0	353.0	32.0
SN74ACT564PWR	TSSOP	PW	20	2000	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

ı	Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
	SN74ACT564N	N	PDIP	20	20	506	13.97	11230	4.32

MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



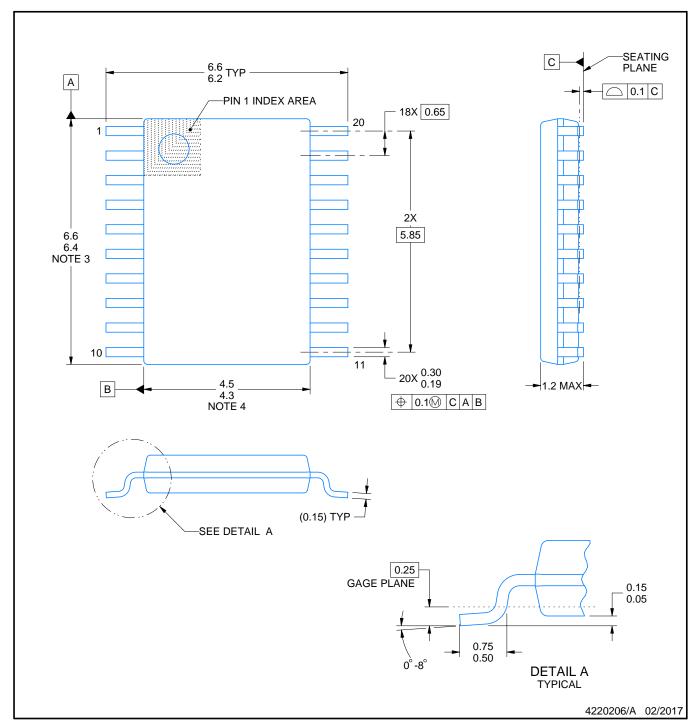
NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE PACKAGE



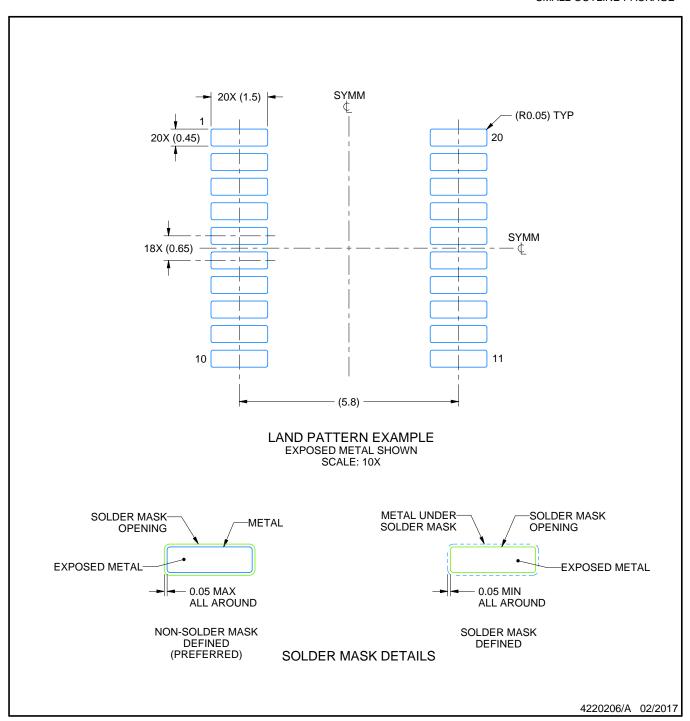
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



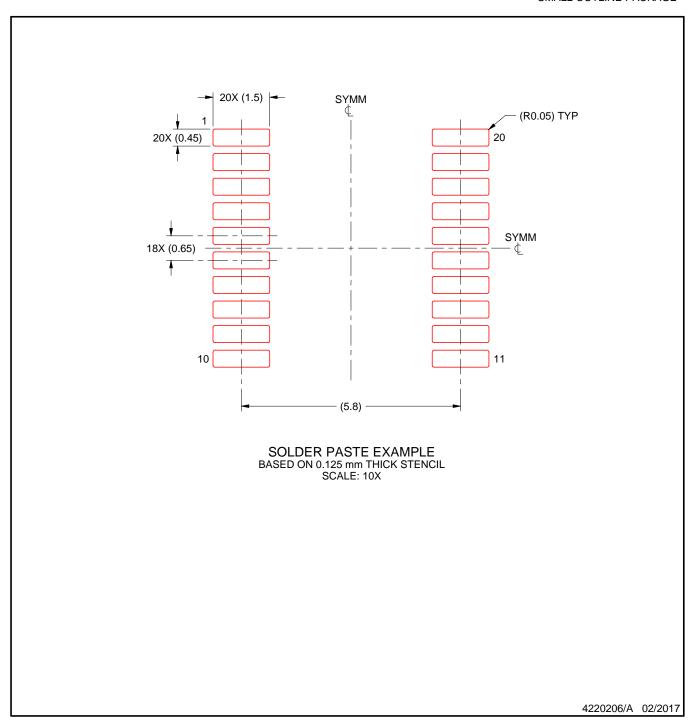
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



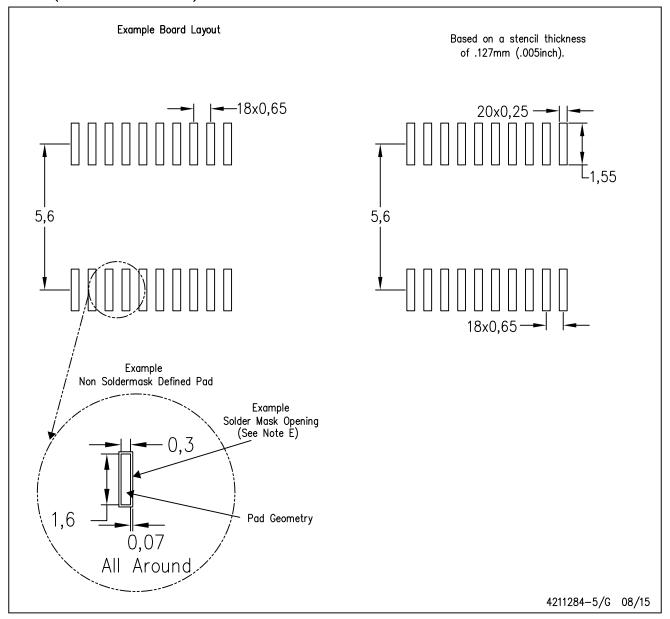
NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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